WHAT IS CLAIMED IS:

1	1. A cleaning system adapted for cleaning semiconductor processing
2	equipment, said cleaning system comprising:
3	a remote dissociator coupled to said equipment by a transport mechanism;
4	a local dissociator integrally related to said equipment; and
5	a precursor disposed in said remote dissociator;
6	wherein said remote dissociator is operable to dissociate said precursor to
7	create a first plurality of cleaning radicals, said cleaning radicals entering said transport
8	mechanism, a first portion of said cleaning radicals entering said equipment and a second
9	portion of said cleaning radicals recombining to create a plurality of less reactive
10	elements in said transport mechanism, said less reactive elements entering said
11	equipment, and said local dissociator operable to dissociate a portion of said less reactive
12	elements to create a second plurality of cleaning radicals.
1	2. The cleaning system of claim 1 further comprising an optical
2	endpoint detector, wherein said detector indicates completion of a cleaning of said
3	equipment.
1	3. The cleaning system of claim 1, wherein said remote dissociator
2	provides a greater than 75% dissociation efficiency, whereby PFCs in an exhaust from
3	said cleaning system are reduced.
1	4. The cleaning system of claim 1, wherein said first portion of said
2	cleaning radicals is less than said second portion of said cleaning radicals.
1	5. The cleaning system of claim 1, wherein said second plurality of
2	cleaning radicals includes ions.
1	6. The cleaning system of claim 5, wherein said cleaning radicals
2	include at least one of: Cl, F, Cl ions, or F ions.
1	7. A method of cleaning a semiconductor processing equipment, said
2	method comprising:
3	introducing a precursor to a dissociator;
4	dissociating said presure or to areate a first abundity of so disale.

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carbon on said equipment to form CO.

	1	18. A method of cleaning a semiconductor processing equipment, said
	2	method comprising:
	3	introducing a first precursor to a remote dissociator;
	4	dissociating said first precursor to create a first plurality of radicals;
	5	introducing said first plurality of radicals to said equipment;
	6	introducing a second precursor to said remote dissociator;
	7	dissociating said second precursor to create a second plurality of radicals;
	8	introducing a first portion of said second plurality of radicals to said
	9	equipment, a second portion of said second plurality of radicals re-associating to create
181	10	less reactive elements;
0		introducing said less reactive elements to said equipment; and
	12	dissociating said less reactive elements to form a third plurality of radicals
100	13	in said equipment.
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1	2	19. The method of claim 18, wherein said third plurality of radicals
	2	comprise Cl and said first plurality of radicals comprise F.
i sh	1	20. The method of claim 18, wherein said dissociating said first
145	2	precursor includes forming a first plasma and said dissociating said less reactive elements
gue.	3	includes forming a second plasma.
	1	21. A semiconductor equipment cleaning system comprising:
	2	 A semiconductor equipment cleaning system comprising: a housing;
	3	- '
	4	a remote dissociator configured to dissociate a first gas remote from said housing, said dissociation forming a second gas;
	5	a gas delivery system to introduce a portion of said first gas, a portion of
	6	said second gas, and a re-associated portion of said second gas into said housing.
	7	a local dissociator configured to dissociate said re-associated portion of
	8	said second gas;
	9	a controller for controlling said remote dissociator, said gas delivery
1	0	system, and said local dissociator; and
1	1	a memory coupled to said controller, said memory comprising a computer-
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readable medium having a computer-readable program embodied therein for directing

	13	operation of said semiconductor cleaning system, said computer-readable program
	14	comprising:
	15	an instruction to control said remote dissociator;
	16	an instruction to control said gas delivery system; and
	17	an instruction to control said local dissociator.
	1	22. A computer-readable storage medium having a computer-readable
	2	program embodied therein for directing operation of a semiconductor cleaning system,
	3	said semiconductor cleaning system comprising an equipment, a remote dissociator, a
	4	local dissociator, and a gas delivery system configured to introduce a gas from said
	5	remote dissociator into said equipment, said computer-readable program including
	6	instructions for operating said semiconductor cleaning system in accordance with the
1 1 1 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2	7	following:
Day.	8	introducing a precursor to said remote dissociator;
[Jil	9	dissociating said precursor to create a first plurality of radicals;
98 1		introducing a first portion of said first plurality of radicals to said
12 1 145	11	equipment by way of said gas delivery system, a second portion of said first plurality of
1/4/2	12	radicals re-associating to create less reactive elements;
Land 1	.3	introducing said less reactive elements to said equipment by way of said
had 1	4	gas delivery system; and
1	5	dissociating said less reactive elements to form a second plurality of
1	6	radicals in said equipment.